## White LED Driver with Wide PWM Dimming Range

The ISL97634 represents an efficient and highly integrated PWM boost LED driver that is suitable for $1.8^{\prime \prime}$ to $3.5^{\prime \prime}$ LCDs that employ 2 to 6 white LEDs for backlighting. With integrated Schottky diode, OVP, and wide range of PWM dimming capability, the ISL97634 provides a simple, reliable, and flexible solution to the backlight designers.

The ISL97634 features a wide range of PWM dimming control capability. It allows dimming frequency as low as DC to 32 kHz beyond audible spectrum. The ISL97634 also features a feedback disconnect switch to prevent the output from being modulated by the PWM dimming signal that minimizes system disturbance.

The ISL97634 is available in the 8 Ld TDFN ( $2 \mathrm{~mm} \times 3 \mathrm{~mm}$ ) package. There are $14 \mathrm{~V}, 18 \mathrm{~V}$, and 26 V OVP options that are suitable for 3 LEDS, 4 LEDs, and 6 LEDs backlight applications respectively. The ISL97634 is specified for operation over the $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ ambient temperature at input voltage from 2.4 V to 5.5 V .

## Pinout

ISL97634
(8 LD TDFN)
TOP VIEW


## Typical Application Circuit



## Features

- Drives Up to 6 LEDs in Series
- OVP (14V, 18 V , and 26 V for 3, 4 and 6 LEDs Applications)
- PWM Dimming Control From DC to 32 kHz
- Output Disconnect Switch
- Integrated Schottky Diode
- 2.4 V to 5.5 V Input
- 85\% Efficiency
- 1.4MHz Switching Frequency Allows Small LC
- $1 \mu \mathrm{~A}$ Shutdown Current
- Internally Compensated
- 8 Ld TDFN ( 2 mmx 3 mm )
- Pb-Free Plus Anneal Available (RoHS Compliant)


## Applications

- LED Backlighting for:
- Cell phones
- Smartphones
- MP3
- PMP
- Automotive Navigation Panel
- Portable GPS


## Ordering Information

| PART NUMBER (Note) | PART MARKING | TAPE \& REEL (QTY) | PACKAGE <br> (Pb-free) | PKG. DWG. \# |
| :---: | :---: | :---: | :---: | :---: |
| ISL97634IRT14Z-T | ELE | $\begin{gathered} 13 " \\ (6 \mathrm{k} p \mathrm{pcs} .) \end{gathered}$ | 8 Ld 2x3 TDFN | L8.2x3A |
| ISL97634IRT14Z-TK | ELE | $\begin{gathered} 13 " \\ (1 \mathrm{k} \text { pcs.) } \end{gathered}$ | 8 Ld $2 \times 3$ TDFN | L8.2x3A |
| ISL97634IRT18Z-T | ELF | $\begin{gathered} 13 " \\ (6 \mathrm{k} \text { pcs.) } \end{gathered}$ | 8 Ld $2 \times 3$ TDFN | L8.2x3A |
| ISL97634IRT18Z-TK | ELF | $\begin{gathered} 13 " \\ (1 \mathrm{k} \text { pcs.) } \end{gathered}$ | 8 Ld 2x3 TDFN | L8.2x3A |
| ISL97634IRT26Z-T | ELG | $\begin{gathered} 13 " \\ (6 \mathrm{k} \text { pcs.) } \end{gathered}$ | 8 Ld 2x3 TDFN | L8.2x3A |
| ISL97634IRT26Z-TK | ELG | $\begin{gathered} 13 " \\ (1 \mathrm{k} \text { pcs.) } \end{gathered}$ | 8 Ld 2x3 TDFN | L8.2x3A |

NOTE: Intersil Pb-free plus anneal products employ special Pb-free material sets; molding compounds/die attach materials and $100 \%$ matte tin plate termination finish, which are RoHS compliant and compatible with both SnPb and Pb -free soldering operations. Intersil Pb -free products are MSL classified at Pb-free peak reflow temperatures that meet or exceed the Pb-free requirements of IPC/JEDEC J STD-020.

| Absolute Maximum Ratings ( $\left.\mathrm{T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}\right)$ |  |
| :---: | :---: |
| Input Voltage ( $\mathrm{V}_{\mathrm{IN}}$ ) | -0.3V to 6 V |
| LX Voltage | . 0.3 V to 28 V |
| FBSW Voltage | .-0.3V to 28V |
| All Other Pins | -0.3V to 6V |

## Operating Conditions

Temperature Range $\qquad$ $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$

## Thermal Information

| Thermal Resistance | $\theta_{\mathrm{JA}}\left({ }^{\circ} \mathrm{C} / \mathrm{W}\right)$ | $\theta_{\mathrm{JC}}\left({ }^{\circ} \mathrm{C} / \mathrm{W}\right)$ |
| :---: | :---: | :---: |
| TDFN Package (Notes 1, 2). | 77 | 12 |
| Maximum Junction Temperature |  | $+125^{\circ} \mathrm{C}$ |
| Storage Temperature |  | to $+150^{\circ} \mathrm{C}$ |
| Lead Temperature (Soldering 10s) |  | $+300^{\circ} \mathrm{C}$ |

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

IMPORTANT NOTE: All parameters having Min/Max specifications are guaranteed over temperature of $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$ unless otherwise stated. Typ values are for information purposes only at $T J=T C=T A=+25^{\circ} \mathrm{C}$.
NOTE:

1. $\theta_{\mathrm{JA}}$ is measured in free air with the component mounted on a high effective thermal conductivity test board with "direct attach" features. See Tech Brief TB379.
2. For $\theta_{\mathrm{JC}}$, the "case temp" location is the center of the exposed metal pad on the package underside.

## Electrical Specifications $\quad V_{I N}=V_{P W M / E N}=3 V$

| PARAMETER | DESCRIPTION | CONDITION | MIN | TYP | MAX | UNIT |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{V}_{\mathrm{IN}}$ | Supply Voltage |  | 2.4 |  | 5.5 | V |
| IIN | Supply Current | PWM/EN $=3 \mathrm{~V}$, enabled, not switching |  | 0.8 | 1.5 | mA |
|  |  | PWM/EN = OV, disabled |  |  | 1 | $\mu \mathrm{A}$ |
| ${ }^{\text {f }}$ W | Switching Frequency |  | 1,300 | 1,450 | 1,600 | kHz |
| DMAX | Maximum Switching Duty Cycle |  | 90 | 95 |  | \% |
| ILIM | LX Current |  | 400 | 470 |  | mA |
| RSW(LX) | LX Switch ON-Resistance | $\mathrm{ILX}=100 \mathrm{~mA}$ |  | 900 |  | $\mathrm{m} \Omega$ |
| ILEAK | LX Switch Leakage Current | $\mathrm{VLX}=28 \mathrm{~V}$ |  | 0.01 | 1 | $\mu \mathrm{A}$ |
| VFB | Feedback Voltage |  | 90 | 95 | 100 | mV |
| IFB | FB Pin Bias Current | $V F B=95 \mathrm{mV}$ |  |  | 1 | $\mu \mathrm{A}$ |
| $\mathrm{R}_{\text {SW(FBSW }}$ ) | FBSW Switch ON-Resistance |  |  | 10 |  | $\Omega$ |
| V DIODE | Schottky Diode Forward Voltage | IDIODE $=100 \mathrm{~mA}, \mathrm{~T}_{\mathrm{A}}=+25^{\circ} \mathrm{C}$ | 600 |  | 850 | mV |
| OVP | Overvoltage Protection | ISL97634IRT14Z | 14 |  |  | V |
|  |  | ISL97634IRT18Z | 18 |  |  | V |
|  |  | ISL97634IRT26Z | 26 |  | 28 | V |
| VIL | Logic Low Voltage of PWM/EN |  |  |  | 0.6 | V |
| VIH | Logic High Voltage of PWM/EN |  | 1.5 |  |  | V |

## Block Diagram



## Pin Description

| PIN <br> NUMBER | PIN <br> NAME |  |
| :---: | :---: | :--- |
| 1 | GND | Ground Pin. Connect to local ground. |
| 2 | VIN | Input Supply Pin. Connect to the input supply voltage, the inductor and the input supply decoupling capacitor. |
| 3 | NWM/EN | PWM or Enable Pin. Connect external PWM signal allows pulse width modulation current operation. Enable <br> signal allows peak current operation or disable signal shuts down the device. |
| 4 | FB | Fo Connect <br> Feedback Pin. Connect the sense resistor between FB and ground. The cathode of bottom LED can also <br> 5 |
| 6 | FBSW | FB Disconnect Switch. Connect to the cathode of the bottom LED if the output current to be PWMed. |
| 7 | VOUT | Output Pin. Connect to the anode of the top LED and the output filter capacitor. |
| 8 | LX | Switching Pin. Connect to inductor. |

Typical Performance Curves


FIGURE 1. EFFICIENCY vs PWM DUTY CYCLE


FIGURE 3. LOAD REGULATION $\left(\mathrm{V}_{\mathrm{IN}}=4 \mathrm{~V}\right)$


FIGURE 5. DIMMNG LINEARITY (FB VOLTAGE) vs DUTY CYCLE


FIGURE 2. QUIESCENT CURRENT vs $\mathrm{V}_{\mathrm{IN}}$ (PWM/EN = HI)


FIGURE 4. LINE REGULATION


FIGURE 6. PWM DIMMING AT 1kHz, D = 1\%


FIGURE 7. PWM DIMMING AT 1kHz, D = 1\% ZOOM IN


FIGURE 8. PWM DIMMING AT $1 \mathrm{kHz}, \mathrm{D}=99 \%$


FIGURE 9. PWM DIMMING AT $20 \mathrm{kHz}, \mathrm{D}=\mathbf{5 0 \%}$

## Detailed Description

The ISL97634 uses a constant frequency, current mode control scheme to provide excellent line and load regulation. There are three OVP models for driving 3,4 , and 6 LEDs and their OVP thresholds are set at $14 \mathrm{~V}, 18 \mathrm{~V}$, and 26 V respectively. The ISL97634 operates from an input voltage of 2.4 V to 5.5 V and ambient temperature from $-40^{\circ} \mathrm{C}$ to $+85^{\circ} \mathrm{C}$. The switching frequency is around 1.45 MHz and allows the driver circuit to employ small LC components. The peak forward current of the LED is set using the $\mathrm{R}_{\text {SET }}$ resistor. In the steady state mode, the LED peak current is given by the following equation:
$\mathrm{I}_{\mathrm{LED}}=\frac{\mathrm{V}_{\mathrm{FB}}}{\mathrm{R}_{\mathrm{SET}}}$

## PWM Dimming

The ISL97634's PWM/EN pin can be tied permanently to high for a fixed current operation. On the other hand, the ISL97634 can be applied with an external PWM signal to
pulse width modulated the output current. It is well understood that the LED brightness is a linear function of the LED current. In addition, the average LED current corresponds to the duty cycle "D" of the PWM signal as:
$\mathrm{I}_{\text {LED-AVG }}=\frac{\mathrm{V}_{\mathrm{FB}}}{\mathrm{R}_{\mathrm{SET}}} \cdot \mathrm{D}$
As a result, PWM signal provides a means to dim the LED brightness. PWM dimming offers the best LEDs matching over DC dimming. It is because the LED peak current operating point is far away from the knee of the diode I-V curve where part to part variations are high. The PWM dimming test results are shown in Figure 6 with two PWM frequencies, 1 kHz and 20 kHz . The vertical scale parameter FB is proportional to the current and therefore the brightness.
For the ISL97634, PWM dimming provides linear dimming adjustment with low frequency signal, such as 1 kHz and below. The applied PWM dimming signal can be up to 32 kHz
; however, the dimming linearity is compromised at low duty cycles as their durations are too short for the ISL97634's control loop to respond properly. This non ideality behavior does not cause any functional problem. The PWM dimming linear responses in Figure 5 are expanded in Figure 10. At 1 kHz PWM dimming, the duty cycle can virtually vary from below $1 \%$ to DC . On the other hand, at 20 kHz PWM dimming, the linearity range is from $5 \%$ to DC only.


FIGURE 10. DIMMING LINEARITY vs DUTY CYCLES ZOOM IN
The low level non-linearity effects at high frequency PWM dimming is also reflected in the efficiency measurements in Figure 11.


FIGURE 11. EFFICIENCY vs PWM DIMMING FREQUENCIES

## Feedback Disconnect Switch

The ISL97634 functions properly without using the FBSW. However, the output capacitor will discharge during the PWM off time resulting in poor dimming linearity at low duty cycles. The output discharge effect can be seen in Figure 12. Moreover, the output is modulated by the PWM signal that may create interference to other systems.
only rated for the required voltage range can therefore be


FIGURE 12. PWM DIMMING AT 1kHz WITHOUT USING FBSW
The FBSW should be used for PWM dimming as illustrated in "Typical Application Circuit" on page 1. During the PWM off time, the FBSW is opened. The LEDs are floating and therefore the output capacitor has no path to discharge. The LED current responds accurately with the PWM signal (see Figure 13). The output switches very quickly to the target current with minimal settling ringing and without being modulated by the PWM signal and therefore minimizes any system disturbance.


FIGURE 13. PWM DIMMING AT 1kHz USING FBSW

## Overvoltage Protection

The ISL97634 comes with overvoltage protection. The OVP trip points are at $14 \mathrm{~V}, 18 \mathrm{~V}$, and 26 V for ISL97634IRT14Z, ISL97634IRT18Z, and ISL97634IRT26Z respectively. The maximum numbers of LEDs and OVP threshold are shown in Table 1. When the device reaches the OVP, the LX stops switching, disabling the boost circuit until $\mathrm{V}_{\mathrm{OUT}}$ falls about $7 \%$ below the OVP threshold. At this point, LX will be allowed to switch again. The OVP event will not cause the device to shutdown.

There are three OVP options so that the 3 LEDs application should use the 14 V OVP device and the 6 LEDs application should use the 26 V OVP device. An output capacitor that is used, which will optimize the component costs in some cases.

TABLE 1.

| PART NO. | OVP | MAX NO. OF <br> LEDS | MAX ILED |
| :---: | :---: | :---: | :---: |
| ISL97634IRT14Z | 14 V | 3 | 70 mA |
| ISL97634IRT18Z | 18 V | 4 | 50 mA |
| ISL97634IRT26Z | 26 V | 6 | 30 mA |

## Shutdown

When PWM/EN is taken low the ISL97634 enters into the power down mode where the supply current is reduced to less than $1 \mu \mathrm{~A}$. The device resumes normal when the PWM/EN goes high.

## Components Selection

The input capacitance is typically $0.22 \mu \mathrm{~F}$. The output capacitor should be in the range of $0.22 \mu \mathrm{~F}$ to $1 \mu \mathrm{~F}$. X5R or X7R type of ceramic capacitors of the appropriate voltage rating are recommended.

When choosing an inductor, make sure the average and peak current ratings are adequate by using the following formulas (80\% efficiency assumed):
$\mathrm{I}_{\text {LAVG }}=\frac{\mathrm{I}_{\text {LED }} \cdot \mathrm{V}_{\mathrm{OUT}}}{0.8 \cdot \mathrm{~V}_{\mathrm{IN}}}$
$\mathrm{I}_{\mathrm{LPK}}=\mathrm{I}_{\mathrm{LAVG}}+\frac{1}{2} \cdot \Delta \mathrm{I}_{\mathrm{L}}$
$\Delta \mathrm{I}_{\mathrm{L}}=\frac{\mathrm{V}_{\text {IN }} \cdot\left(\mathrm{V}_{\text {OUT }}-\mathrm{V}_{\text {IN }}\right)}{\mathrm{L} \cdot \mathrm{V}_{\text {OUT }} \cdot \mathrm{f}_{\mathrm{OSC}}}$
Where:

- $\Delta I_{L}$ is the peak-to-peak inductor current ripple in Amps
- $L$ is the inductance in $H$.
- $\mathrm{f}_{\mathrm{OSC}}$ is the switching frequency, typically 1.45 MHz

The ISL97634 supports a wide range of inductance values $(10 \mu \mathrm{H} \sim 82 \mu \mathrm{H})$. For lower inductor values or lighter loads, the boost inductor current may become discontinuous. For high boost inductor values, the boost inductor current will be in continuous mode.

In addition to the inductor value and switching frequency, the input voltage, number of LEDs and the LED current also affects whether the converter operates in continuous conduction or discontinuous conduction mode. Both operating modes are allowed and normal. The discontinuous conduction mode yields lower efficiency due to higher peak current.

## Compensation

The product of the output capacitor and the load create a pole while the inductor creates a right half plane zero. Both of these attributes degrade the phase margin but the

ISL97634 has internal compensation network that ensures the device operates reliably under the specified conditions. The internal compensation and the highly integrated functions of the ISL97634 make it a design friendly device to be used in high volume, high reliability applications.

## Applications

## Analog Dimming

Analog dimming is usually not recommended because of the brightness non-linearity at low levels dimming. However, some systems are EMI or noise sensitive that analog dimming may be more suitable than PWM dimming under those situations. The ISL97632 is part of the same family as the ISL97634 and has been designed with a serial interface to give access to 32 separate dimming levels. Alternatively analog dimming can be achieved by applying a variable DC voltage $\left(V_{\text {Dim }}\right)$ at FB pin (see Figure 14) to adjust the LED current. As the DC dimming signal voltage increases above VFB, the voltages drop on R1 and R2 increase and the voltage drop on RSET decreases. Thus, the LED current decreases.
$I_{\text {LED }}=\frac{V_{F B} \cdot\left(R_{1}+R_{2}\right)-V_{\text {Dim }} \cdot R_{1}}{R_{2} \cdot R_{\text {SET }}}$
If $\mathrm{V}_{\text {DIM }}$ is taken below FB , the inverse will happen and the brightness will increase.

The DC dimming signal voltage can be a variable DC voltage from a POT, a DCP (Digitally Controlled Potentiometer), or a DC voltage generated by filtering a high frequency PWM control signal.


FIGURE 14. ANALOG DIMMING CONTROL APPLICATION CIRCUIT

As brightness is directly proportional to LED currents, $\mathrm{V}_{\text {Dim }}$ may be calculated for any desired "relative brightness" (F) using Equation 7:
$v_{\text {Dim }}=\frac{R_{2}}{R_{1}} \cdot v_{F B} \cdot\left(1+\frac{R_{1}}{R_{2}}-F\right)$
Where $\mathrm{F}=\mathrm{I}_{\text {LED }}$ (dimmed)/ILED (undimmed).
These equations are valid for values of R1 and R2 such that both R1>>RSET and R2>>RSET.

The analog dimming circuit can be tailored to a desired relative brightness for different $\mathrm{V}_{\text {Dim }}$ ranges using Equation 8.
$\mathrm{R}_{2}=\frac{\left[\left(\mathrm{V}_{\text {Dim }} \max -\mathrm{V}_{\mathrm{FB}}\right) \cdot \mathrm{R}_{1}\right]}{\left[\mathrm{V}_{\mathrm{FB}} \cdot\left(1-\mathrm{F}_{\text {min }}\right)\right]}$

Where $V_{\text {Dim max }}$ is the maximum $V_{\text {Dim }}$ voltage and $F_{\text {min }}$ is the minimum relative brightness (i.e., the brightness with $V_{\text {Dim_max }}$ applied).
i.e., $V_{\text {Dim_max }}=5 \mathrm{~V}, \mathrm{~F}_{\min }=10 \%$ (i.e., 0.1), $\mathrm{R}_{2}=189 \mathrm{k}$
i.e., $V_{\text {Dim_max }}=1 V, F_{\min }=10 \%$ (i.e., 0.1 ), $R_{2}=35 k$

## Efficiency Improvement

Figure 1 shows the efficiency measurements during PWM operation. The choice of the inductor has a significant impact on the power efficiency. As shown in Equation 4, the higher the inductance, the lower the peak current therefore the lower the conduction and switching losses. On the other hand, it has also a higher series resistance. Nevertheless, the efficiency improvement effect by lowering the peak current is greater than the resistance increases with larger value of inductor. Efficiency can also be improved for systems that have high supply voltages. Since the ISL97634 can only supply from 2.4 V to $5.5 \mathrm{~V}, \mathrm{~V}_{\text {IN }}$ must be separated from the high supply voltage for the boost circuit as shown in Figure 15 and the efficiency improvement is shown in Figure 16.


FIGURE 15. SEPARATE HIGH INPUT VOLTAGE FOR HIGHER EFFICIENCY OPERATION


FIGURE 16. EFFICIENCY IMPROVEMENT WITH 9 AND 12V INPUTS

## 8 LEDs Operation

For medium size LCDs that need more than 6 low power LEDs for backlighting, such as a Portable Media Player or Automotive Navigation Panel displays, the voltage range of the ISL97634 is not sufficient. However, the ISL97634 can be used as an LED controller with an external protection MOSFET connected in cascode fashion to achieve higher output voltage. A conceptual 8 LEDs driver circuit is shown in Figure 17. A 60V logic level N-Channel MOSFET is configured such that its drain ties between the inductor and the anode of schottky diode, its gate ties to the input, and its source ties to the ISL97634 LX node connecting to the drain of the internal switch. When the internal switch turns on, it pulls the source of M1 down to ground, and LX conducts as normal. When the internal switch turns off, the source of M1 will be pulled up by the follower action of M1, limiting the maximum voltage on the ISL97634 LX pin to below Vin, but allowing the output voltage to go much higher than the breakdown limit on the LX pin. The switch current limit and maximum duty cycle will not be changed by this setup, so input voltage will need to be carefully considered to make sure that the required output voltage and current levels are achievable. Because the source of M1 is effectively floating when the internal LX switch is off, the drain-to-source capacitance of M1 may be sufficient to capacitively pull the node high enough to breaks down the gate oxide of M1. To prevent this, VOUT should be connected to VIN, allowing the internal schottky to limit the peak voltage. This will also hold the VOUT pin at a known low voltage, preventing the built in OVP function from causing problems. This OVP function is effectively useless in this mode as the real output voltage is outside its intended range. If the user wants to implement their own OVP protection (to prevent damage to the output capacitor, they should insert a zener from vout to the FB pin. In this setup, it would be wise not to use the FBSW to FB switch as otherwise the zener will have to be a high power one capable of dissipating the entire LED load power. Then the LED stack can then be connected directly to the sense resistor and via a 10 k resistor to FB. A zener can be placed from Vout to the FB pin allowing an over voltage event to pull up on FB with a low breakdown current (and thus low power zener) as a result of the 10 k resistor.


FIGURE 17. CONCEPTUAL 8 LEDs HIGH VOLTAGE DRIVER

## SEPIC Operation

For applications where the output voltage is not always above the input voltage, a buck or boost regulation is needed. A SEPIC (Single Ended Primary Inductance Converter) topology, shown in Figure 18, can be considered for such application. A single cell Li-lon battery operating a cellular phone backlight or flashlight is one example. The battery voltage is between 2.5 V and 4.2 V , depending on the state of charge. On the other hand, the output may require only one 3 V to 4 V medium power LED for illumination because the light guard of the backlight assembly is optimized for cost efficiency trade-off reason.

In fact, a SEPIC configured LED driver is flexible enough to allow the output to be well above or below the input voltage, unlike the previous example. Another example is when the number of LEDs and input requirements are different from platform to platform, a common circuit and PCB that fit all the platforms in some cases may be beneficial enough that it outweighs the disadvantage of adding additional component cost. L1 and L2 can be a coupled inductor in one package.


FIGURE 18. SEPIC LED DRIVER
The simplest way to understand SEPIC topology is to think about it as a boost regulator where the input voltage is level shifted downward at the same magnitude and the lowest reference level starts at $-\mathrm{V}_{\mathrm{IN}}$ rather than OV .

The SEPIC works as follows; assume the circuit in Figure 18 operates normally, when the ISL97634 internal switch opens and it is in the PWM off state, after a short duration where few LC time constants elapsed, the circuit is considered in the steady-state within the PWM off period that L1 and L2 are shorted. $V_{B}$ is therefore shorted to the ground and $C 3$ is charged to $\mathrm{V}_{\mathrm{IN}}$ with $\mathrm{V}_{\mathrm{A}}=\mathrm{V}_{\mathrm{IN}}$. When the ISL97634 internal switch closes and the circuit is in the PWM on state, $\mathrm{V}_{\mathrm{A}}$ is now pulled to ground. Since the voltage in C3 cannot be changed instantaneously, therefore $\mathrm{V}_{\mathrm{B}}$ is shifted downward and becomes $-\mathrm{V}_{\mathrm{IN}}$. The next cycle when the ISL97634 switch opens, $\mathrm{V}_{\mathrm{B}}$ boosts up to the targeted output like the standard boost regulator operation, except the lowest reference point is at $-\mathrm{V}_{\mathrm{IN}}$. The output is approximated as:

$$
\begin{equation*}
V_{\text {OUT }}=V_{\text {IN }} \frac{D}{(1-D)} \tag{EQ.9}
\end{equation*}
$$

where D is the on-time of the PWM duty cycle.
The convenience of SEPIC comes with some trade off in addition to the additional $L$ and $C$ costs. The efficiency is usually lowered because of the relatively large efficiency loss through the Schottky diode if the output voltage is low. The L2 series resistance also contributes additional loss. Figure 19 shows the efficiency measurement of a single LED application as the input varies between 2.7 V and 4.2 V .

Note $\mathrm{V}_{\mathrm{B}}$ is considered the level-shifted LX node of a standard boost regulator. The higher the input voltage, the lower the $V_{B}$ voltage will be during PWM on period. The result is that the efficiency will be lower at higher input voltages because the SEPIC has to work harder to boost up to the required level. This behavior is the opposite to the standard boost regulator's and the comparison is shown in Figure 19.


FIGURE 19. EFFICIENCY MEASUREMENT OF A SINGLE LED SEPIC DRIVER

## PCB Layout Considerations

The layout is very important for the converter to function properly. $\mathrm{R}_{\mathrm{SET}}$ must be located as close as possible to the FB and GND pins. Longer traces to the LEDs are acceptable. Similarly, the supply decoupling cap and the output filter cap should be as close as possible to the $\mathrm{V}_{\text {IN }}$ and $\mathrm{V}_{\text {OUT }}$ pins.

The heat of the IC is mainly dissipated through the thermal pad of the package. Maximizing the copper area connected to this pad if possible. In addition, a solid ground plane is always helpful for the EMI performance.

Thin Dual Flat No-Lead Plastic Package (TDFN)


L8.2x3A
8 LEAD THIN DUAL FLAT NO-LEAD PLASTIC PACKAGE

| SYMBOL | MILLIMETERS |  |  | NOTES |
| :---: | :---: | :---: | :---: | :---: |
|  | MIN | NOMINAL | MAX |  |
| A | 0.70 | 0.75 | 0.80 | - |
| A1 | - | - | 0.05 | - |
| A3 | 0.20 REF |  |  | - |
| b | 0.20 | 0.25 | 0.32 | 5,8 |
| D | 2.00 BSC |  |  | - |
| D2 | 1.50 | 1.65 | 1.75 | 7,8 |
| E | 3.00 BSC |  |  | - |
| E2 | 1.65 | 1.80 | 1.90 | 7,8 |
| e | 0.50 BSC |  |  | - |
| k | 0.20 | - | - | - |
| L | 0.30 | 0.40 | 0.50 | 8 |
| N | 8 |  |  | 2 |
| Nd | 4 |  |  | 3 |

Rev. 0 6/04
NOTES:

1. Dimensioning and tolerancing conform to ASME Y14.5-1994.
2. $N$ is the number of terminals.
3. Nd refers to the number of terminals on $D$.
4. All dimensions are in millimeters. Angles are in degrees.
5. Dimension $b$ applies to the metallized terminal and is measured between 0.25 mm and 0.30 mm from the terminal tip.
6. The configuration of the pin \#1 identifier is optional, but must be located within the zone indicated. The pin \#1 identifier may be either a mold or mark feature.
7. Dimensions D2 and E2 are for the exposed pads which provide improved electrical and thermal performance.
8. Nominal dimensions are provided to assist with PCB Land Pattern Design efforts, see Intersil Technical Brief TB389.

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